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Contact us

50 Ω RF Digital Attenuator
5-bit, 15.5 dB, DC – 4.0 GHz

Product Description

The PE4305 is a high linearity, 5-bit RF Digital Step Attenuator (DSA) covering a 15.5 dB attenuation range in 0.5 dB steps, and is pin compatible with the PE430x series. This 50-ohm RF DSA provides both parallel (latched or direct mode) and serial CMOS control interface, operates on a single 3-volt supply and maintains high attenuation accuracy over frequency and temperature. It also has a unique control interface that allows the user to select an initial attenuation state at power-up. The PE4305 exhibits very low insertion loss and low power consumption. This functionality is delivered in a 4x4 mm QFN footprint.

The PE4305 is manufactured on Peregrine's UltraCMOS™ process, a patented variation of silicon-on-insulator (SOI) technology on a sapphire substrate, offering the performance of GaAs with the economy and integration of conventional CMOS.
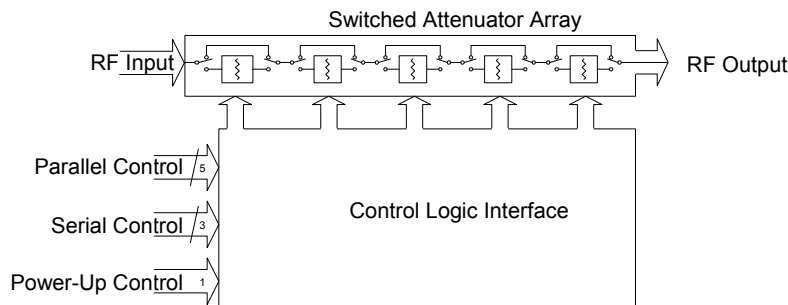
Features
- Attenuation: 0.5 dB steps to 15.5 dB
- Flexible parallel and serial programming interfaces
- Latched or direct mode
- Unique power-up state selection
- Positive CMOS control logic
- High attenuation accuracy and linearity over temperature and frequency
- Very low power consumption
- Single-supply operation
- 50 Ω impedance
- Pin compatible with PE430x series
- Packaged in a 20 Lead 4x4 mm QFN

Figure 1. Functional Schematic Diagram

Figure 2. Package Type
4x4 mm 20-Lead QFN

Table 1. Electrical Specifications @ +25°C, V_{DD} = 3.0 V

| Parameter	Test Conditions	Frequency	Minimum	Typical	Maximum	Units
Operation Frequency			DC		4000	MHz
Insertion Loss[2]		DC - 2.2 GHz	-	1.5	2.25	dB
Attenuation Accuracy	Any Bit or Bit Combination	DC - 2.2 GHz	-	-	±(0.25 + 3% of atten setting) not to exceed ± 0.4 dB	dB
1 dB Compression[3]		1 MHz - 2.2 GHz	30	34	-	dBm
Input IP3[1, 2]	Two-tone inputs +18 dBm	1 MHz - 2.2 GHz	-	52	-	dBm
Return Loss		DC - 2.2 GHz	15	20	-	dB
Switching Speed	50% control to 0.5 dB of final value		-	-	1	µs

Notes: 1. Device Linearity will begin to degrade below 1Mhz

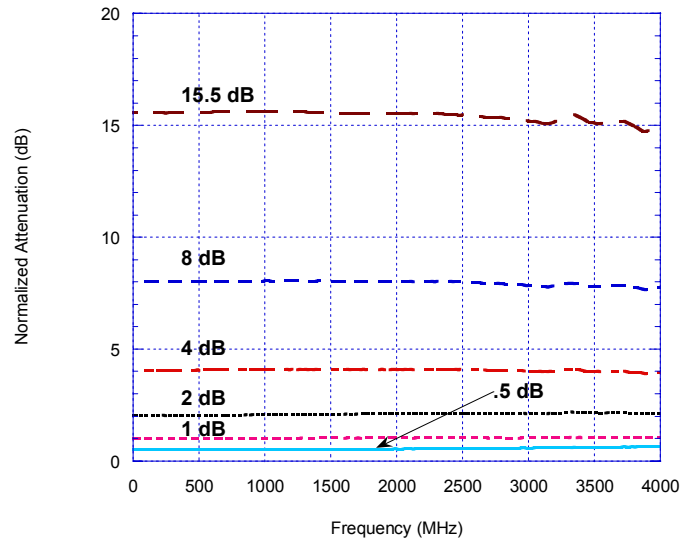2. See Max input rating in Table 3 & Figures on Pages 2 to 4 for data across frequency.

3. Note Absolute Maximum in Table 3.

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Typical Performance Data @ 25°C, V$_{DD}$ = 3.0 V

Figure 3. Insertion Loss

Insertion Loss (dB) vs Frequency (MHz)
- insertion loss @ 25 C
- insertion loss @ -40 C
- insertion loss @ 85 C
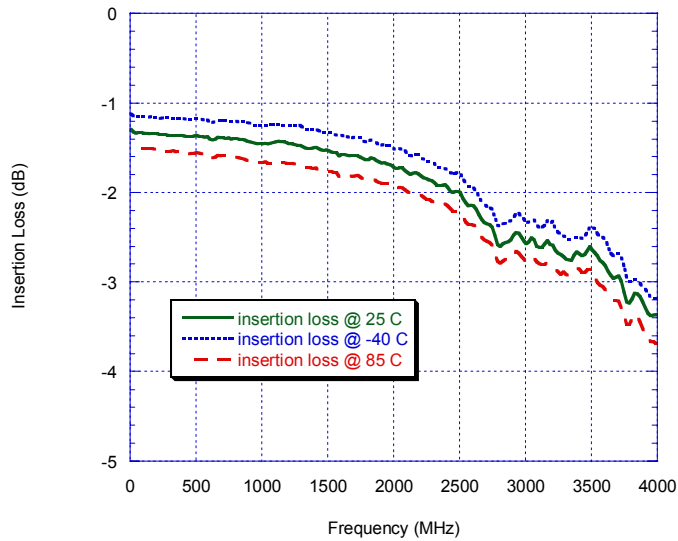
Figure 4. Attenuation at Major steps

Normalized Attenuation (dB) vs Frequency (MHz)
- 15.5 dB
- 8 dB
- 4 dB
- 2 dB
- 1 dB
- .5 dB

**Figure 5. Input Return Loss at Major
               Attenuation Steps**

S11 (dB) vs Frequency (MHz)
- 8 dB
- 15.5 dB
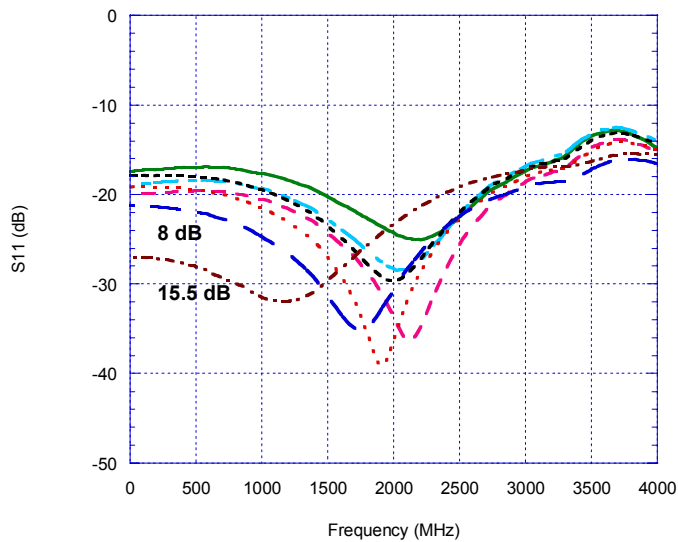
**Figure 6. Output Return Loss at Major
               Attenuation Steps**

S22 (dB) vs Frequency (MHz)
- 15.5 dB

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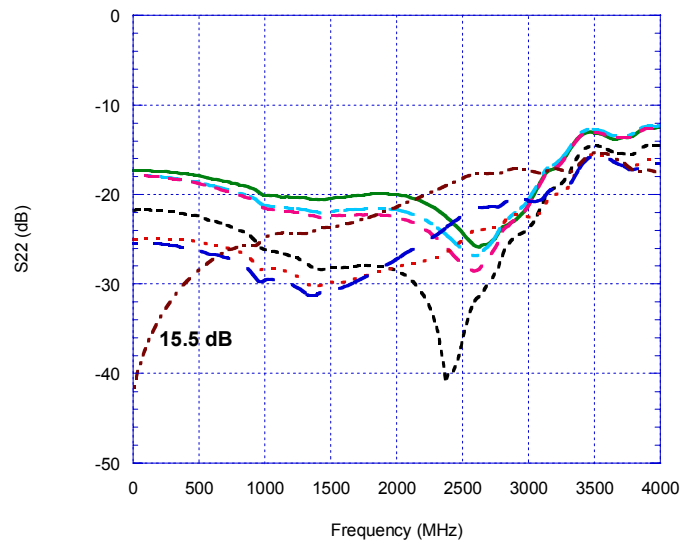
Typical Performance Data @ 25°C, V_{DD} = 3.0 V
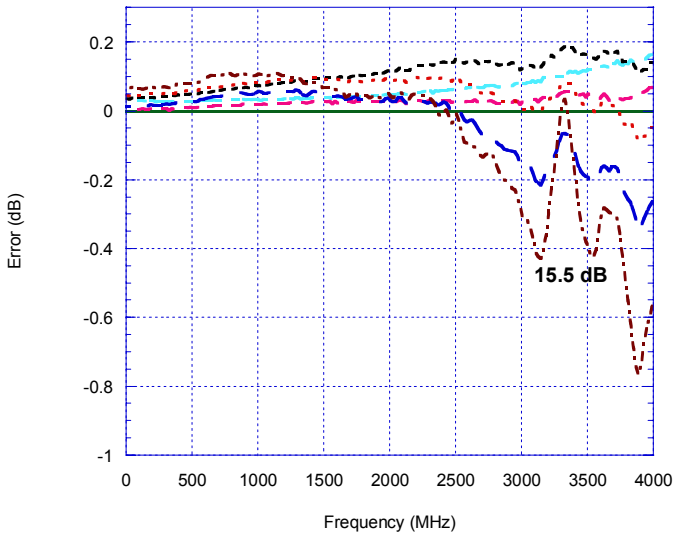
Figure 7. Attenuation Error Vs. Frequency

Figure 8. Attenuation Error Vs. Attenuation Setting at 10 MHz and 510 MHz
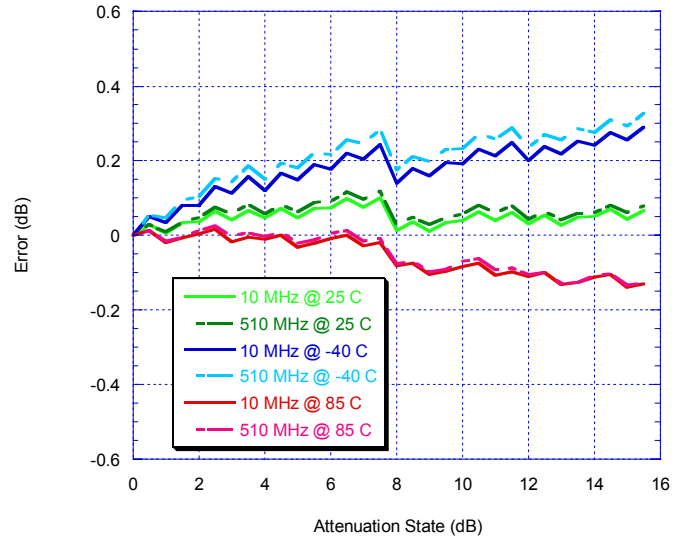

Figure 9. Attenuation Error Vs. Attenuation Setting 1010 MHz and 1210 MHz
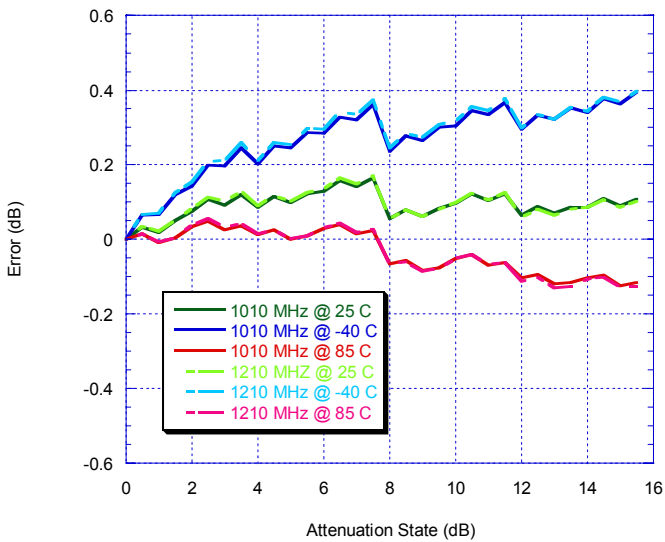

Figure 10. Attenuation Error Vs. Attenuation Setting at 1510 MHz and 2010 MHz
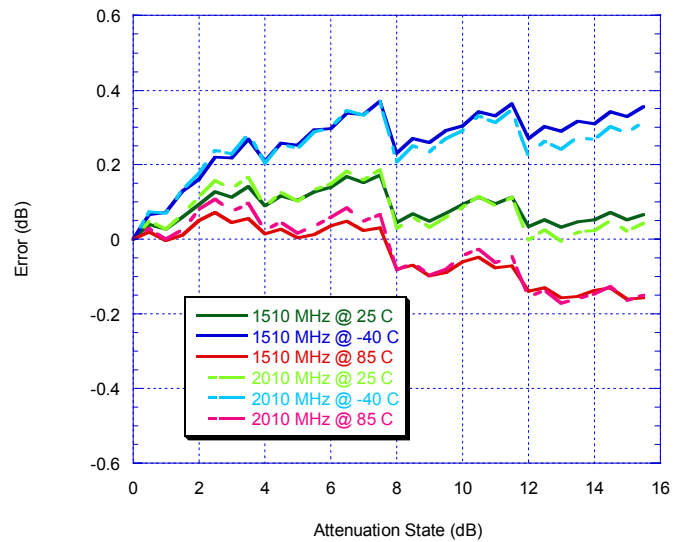
Note: Positive attenuation error indicates higher attenuation than target value

Typical Performance Data @ 25°C, V_{DD} = 3.0 V

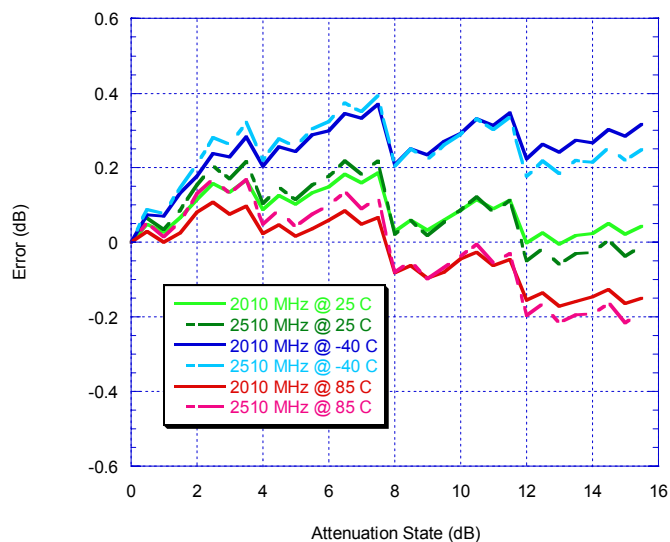### Figure 11. Attenuation Error vs. Attenuation Setting at 2010 MHz and 2510 MHz

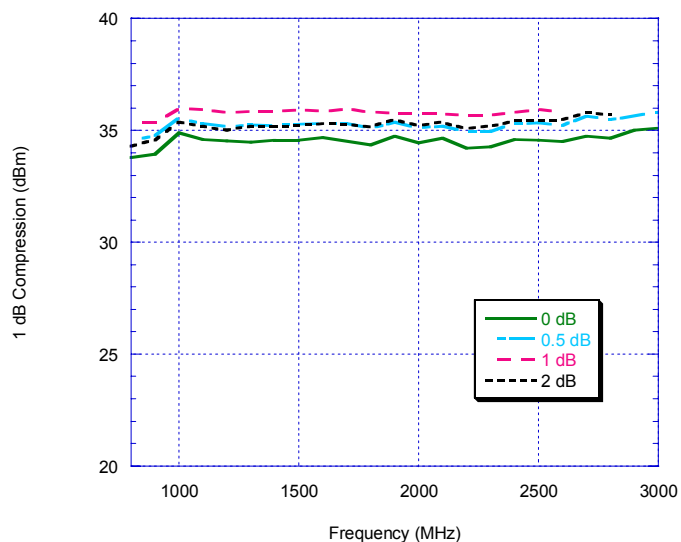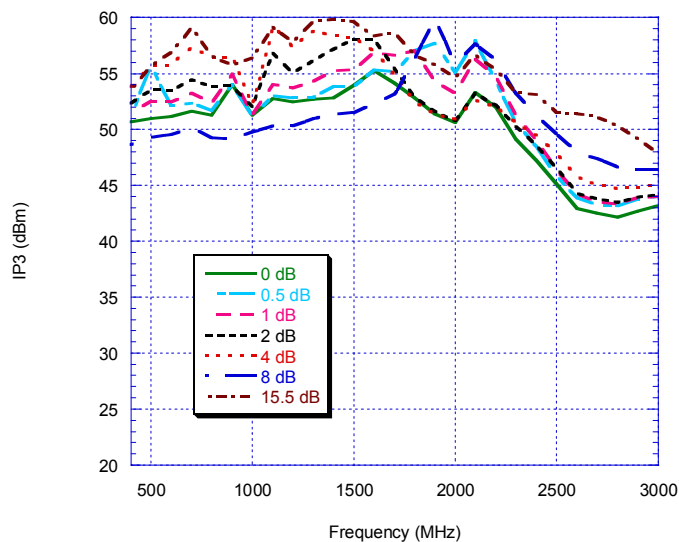### Figure 12. 1 dB Compression vs. Frequency

Figure 13. Input IP3 vs. Frequency

Note: Positive attenuation error indicates higher attenuation than target value
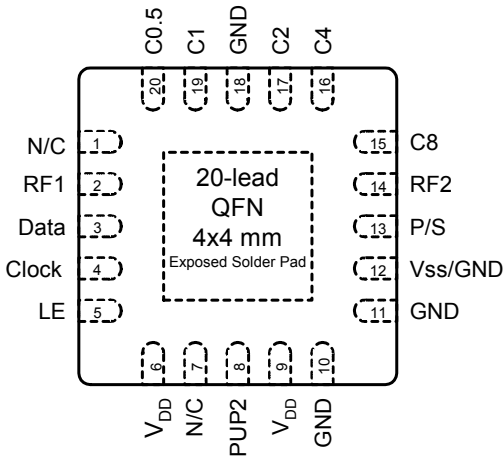
Figure 14. Pin Configuration (Top View)

Table 2. Pin Descriptions

Pin No.	Pin Name	Description
1	N/C	No connect. Can be connected to any bias.
2	RF1	RF port (Note 1).
3	Data	Serial interface data input (Note 4).
4	Clock	Serial interface clock input.
5	LE	Latch Enable input (Note 2).
6	V_{DD}	Power supply pin.
7	N/C	No connect. Can be connected to any bias.
8	PUP2	Power-up selection bit.
9	V_{DD}	Power supply pin.
10	GND	Ground connection.
11	GND	Ground connection.
12	V_{ss}/GND	Negative supply voltage or GND connection(Note 3)
13	P/S	Parallel/Serial mode select.
14	RF2	RF port (Note 1).
15	C8	Attenuation control bit, 8 dB.
16	C4	Attenuation control bit, 4 dB.
17	C2	Attenuation control bit, 2 dB.
18	GND	Ground connection.
19	C1	Attenuation control bit, 1 dB.
20	C0.5	Attenuation control bit, 0.5 dB.
Paddle	GND	Ground for proper operation

Note 1: Both RF ports must be held at 0 VDC or DC blocked with an external series capacitor.

2: Latch Enable (LE) has an internal 100 kΩ resistor to VDD.

3: Connect pin 12 to GND to enable internal negative voltage generator. Connect pin 12 to VSS (-VDD) to bypass and disable internal negative voltage generator.

4. Place a 10 kΩ resistor in series, as close to pin as possible to avoid frequency resonance. See "Resistor on Pin 3" paragraph.

Table 3. Absolute Maximum Ratings

Symbol	Parameter/Conditions	Min	Max	Units
V_{DD}	Power supply voltage	-0.3	4.0	V
V_I	Voltage on any DC input	-0.3	V_{DD}+ 0.3	V
T_{ST}	Storage temperature range	-65	150	°C
P_{IN}	Input power (50Ω)		+30	dBm
V_{ESD}	ESD voltage (Human Body Model)		500	V

Exceeding absolute maximum ratings may cause permanent damage. Operation should be restricted to the limits in the Operating Ranges table. Operation between operating range maximum and absolute maximum for extended periods may reduce reliability.

Table 4. Operating Ranges

Parameter	Min	Typ	Max	Units
V_{DD} Power Supply Voltage	2.7	3.0	3.3	V
I_{DD} Power Supply Current			100	µA
Digital Input High	$0.7xV_{DD}$			V
Digital Input Low			$0.3xV_{DD}$	V
Digital Input Leakage			1	µA
Input Power			+24	dBm
Temperature range	-40		85	°C

Exposed Solder Pad Connection
The exposed solder pad on the bottom of the package must be grounded for proper device operation.

Electrostatic Discharge (ESD) Precautions
When handling this UltraCMOS™ device, observe the same precautions that you would use with other ESD-sensitive devices. Although this device contains circuitry to protect it from damage due to ESD, precautions should be taken to avoid exceeding the rate specified in Table 3.

Latch-Up Avoidance
Unlike conventional CMOS devices, UltraCMOS™ devices are immune to latch-up.

Switching Frequency
The PE4305 has a maximum 25 kHz switching rate.

Resistor on Pin 3

A 10 kΩ resistor on the input to Pin 3 (see Figure 16) will eliminate package resonance between the RF input pin and the digital input. Specified attenuation error versus frequency performance is dependent upon this condition.

Programming Options

Parallel/Serial Selection
Either a parallel or serial interface can be used to control the PE4305. The P/S bit provides this selection, with P/S=LOW selecting the parallel interface and P/S=HIGH selecting the serial interface.

Parallel / Direct Mode Interface
The parallel interface consists of five CMOS-compatible control lines that select the desired attenuation state, as shown in Table 5.

The parallel interface timing requirements are defined by Figure 18 (Parallel Interface Timing Diagram), Table 9 (Parallel Interface AC Characteristics), and switching speed (Table 1).

For parallel programming the Latch Enable (LE) should be held LOW while changing attenuation state control values, then pulse LE HIGH to LOW (per Figure 18) to latch new attenuation state into device.

For direct programming, the Latch Enable (LE) line should be pulled HIGH. Changing attenuation state control values will change device state to new attenuation. Direct Mode is ideal for manual control of the device (using hardwire, switches, or jumpers).

Table 5. Truth Table

P/S	C8	C4	C2	C1	C0.5	Attenuation State
0	0	0	0	0	0	Reference Loss
0	0	0	0	0	1	0.5 dB
0	0	0	0	1	0	1 dB
0	0	0	1	0	0	2 dB
0	0	1	0	0	0	4 dB
0	1	0	0	0	0	8 dB
0	1	1	1	1	1	15.5 dB

Note: Not all 32 possible combinations of C0.5-C8 are shown in table

Serial Interface
The PE4305's serial interface is a 6-bit serial-in, parallel-out shift register buffered by a transparent latch. The latch is controlled by three CMOS-compatible signals: Data, Clock, and Latch Enable (LE). The Data and Clock inputs allow data to be serially entered into the shift register, a process that is independent of the state of the LE input.

The LE input controls the latch. When LE is HIGH, the latch is transparent and the contents of the serial shift register control the attenuator. When LE is brought LOW, data in the shift register is latched.

The shift register should be loaded while LE is held LOW to prevent the attenuator value from changing as data is entered. The LE input should then be toggled HIGH and brought LOW again, latching the new data. The start bit (B5) of the data should always be low to prevent an unknown state in the device. The timing for this operation is defined by Figure 17 (Serial Interface Timing Diagram) and Table 8 (Serial Interface AC Characteristics).

Power-up Control Settings
The PE4305 always assumes a specifiable attenuation setting on power-up. This feature exists for both the Serial and Parallel modes of operation, and allows a known attenuation state to be established before an initial serial or parallel control word is provided.

When the attenuator powers up in Serial mode (P/S=1), the five control bits are set to whatever data is present on the five parallel data inputs (C0.5 to C8). This allows any one of the 32 attenuation settings to be specified as the power-up state.

When the attenuator powers up in Parallel mode (P/S=0) with LE=0, the control bits are automatically set to one of two possible values. These two values are selected by the power-up control bit, PUP2, as shown in Table 6 (Power-Up Truth Table, Parallel Mode).

Table 6. Power-Up Truth Table, Parallel Interface Mode

P/S	LE	PUP2	Attenuation State
0	0	0	Reference Loss
0	0	1	8 dB
0	1	X	Defined by **C0.5-C8**

Note: Power up with LE=1 provides normal parallel operation with C0.5-C8, and PUP2 is not active

Evaluation Kit

The Digital Attenuator Evaluation Kit board was designed to ease customer evaluation of the PE4305 DSA.

J9 is used in conjunction with the supplied DC cable to supply VDD, GND, and –VDD. If use of the internal negative voltage generator is desired, then connect –VDD (black banana plug) to ground. If an external –VDD is desired, then apply -3V.

J1 should be connected to the LPT1 port of a PC with the supplied control cable. The evaluation software is written to operate the DSA in serial mode, so switch 7 (P/S) on the DIP switch SW1 should be ON with all other switches off. Using the software, enable or disable each attenuation setting to the desired combined attenuation. The software automatically programs the DSA each time an attenuation state is enabled or disabled.

To evaluate the Power Up options, first disconnect the control cable from the evaluation board. The control cable must be removed to prevent the PC port from biasing the control pins.

During power up with P/S=1 high and LE=0 or P/S=0 low and LE=1, the default power-up signal attenuation is set to the value present on the five control bits on the five parallel data inputs (C0.5 to C8). This allows any one of the 32 attenuation settings to be specified as the power-up state.

During power up with P/S=0 high and LE=0, the control bits are automatically set to one of two possible values presented through the PUP interface. These two values are selected by the power-up control bit, PUP2, as shown in Table 6. Pins 1 and 7 are open and may be connected to any bias.

Resistor on Pin 3

A 10 kΩ resistor on the input to pin 3 (Figure 16) will eliminate package resonance between the RF input pin and the digital input. Specified attenuation error versus frequency performance is dependent upon this condition.
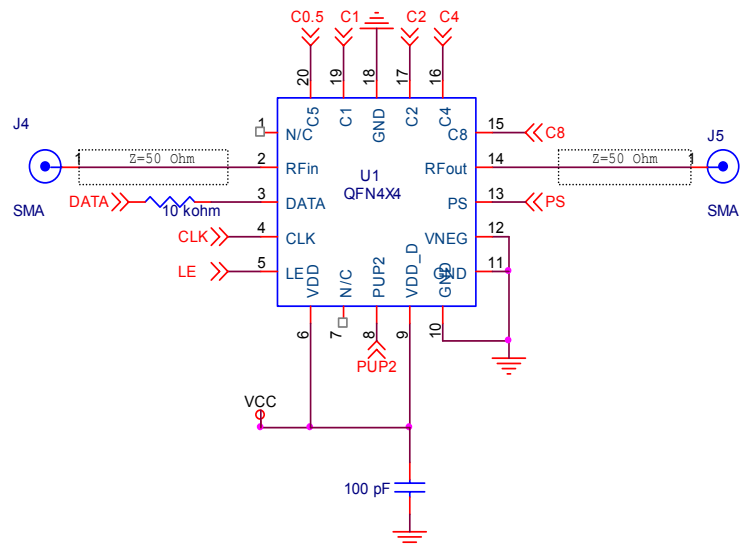
Figure 15. Evaluation Board Layout
Peregrine Specification 101/0112
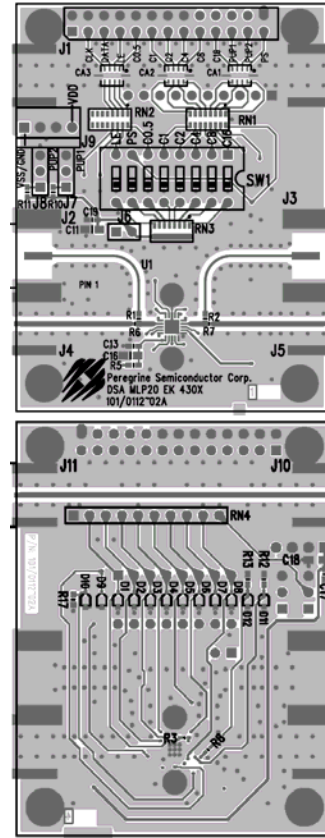
Figure 16. Evaluation Board Schematic
Peregrine Specification 102/0144

Note: Resistor on pin 3 is required and should be placed as close to the part as possible to avoid package resonance and meet error specifications over frequency.
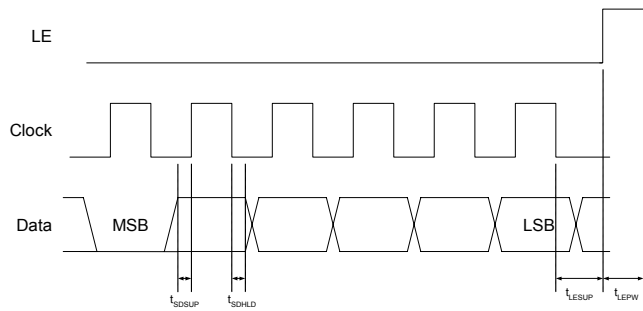
Figure 17. Serial Interface Timing Diagram

Table 7. 5-Bit Attenuator Serial Programming Register Map

B5	B4	B3	B2	B1	B0
0	C8	C4	C2	C1	C0.5

↑ MSB (first in)   ↑ LSB (last in)

Note: The start bit (B5) must always be low to prevent the attenuator from entering an unknown state.

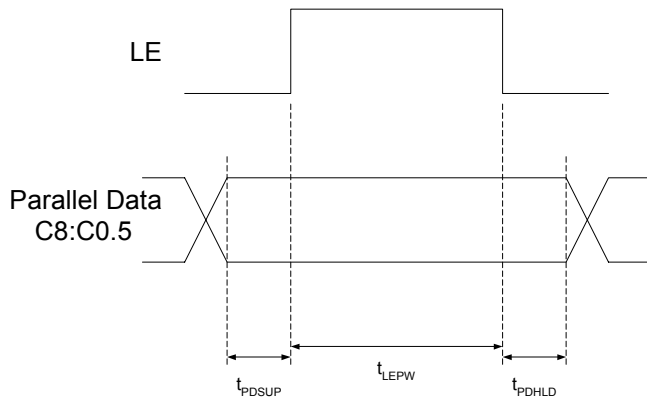## Figure 18. Parallel Interface Timing Diagram

Table 8. Serial Interface AC Characteristics

V_{DD} = 3.0 V, -40° C < T_A < 85° C, unless otherwise specified

| Symbol	Parameter	Min	Max	Unit
f_{Clk}	Serial data clock frequency (Note 1)		10	MHz
t_{ClkH}	Serial clock HIGH time	30		ns
t_{ClkL}	Serial clock LOW time	30		ns
t_{LESUP}	LE set-up time after last clock falling edge	10		ns
t_{LEPW}	LE minimum pulse width	30		ns
t_{SDSUP}	Serial data set-up time before clock rising edge	10		ns
t_{SDHLD}	Serial data hold time after clock falling edge	10		ns

Note: f_{Clk} is verified during the functional pattern test. Serial programming sections of the functional pattern are clocked at 10 MHz to verify fclk specification.

Table 9. Parallel Interface AC Characteristics

V_{DD} = 3.0 V, -40° C < T_A < 85° C, unless otherwise specified

Symbol	Parameter	Min	Max	Unit
t_{LEPW}	LE minimum pulse width	10		ns
t_{PDSUP}	Data set-up time before rising edge of LE	10		ns
t_{PDHLD}	Data hold time after falling edge of LE	10		ns

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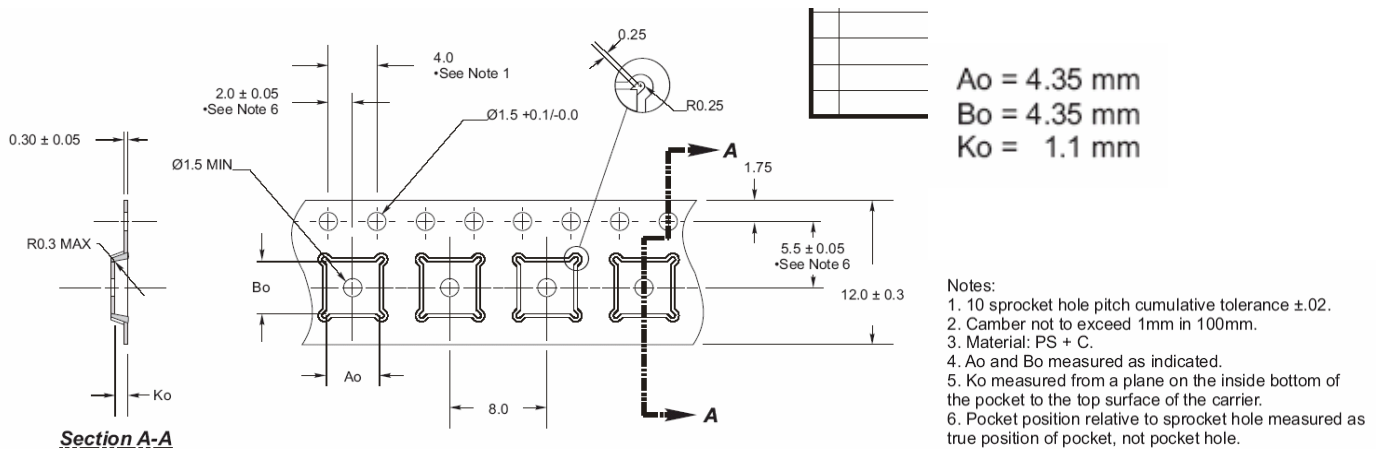
Figure 19. Package Drawing
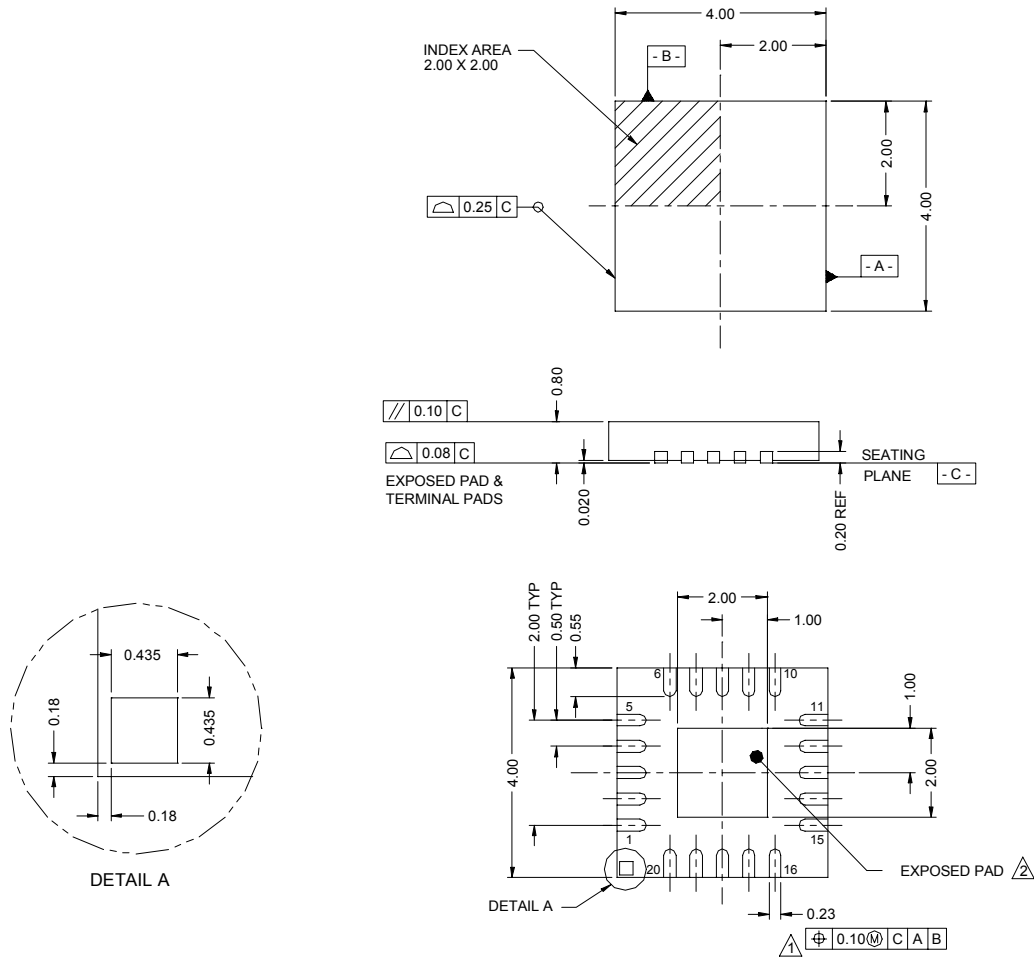
1. Dimension applies to metallized terminal and is measured
between 0.25 and 0.30 from terminal tip.
2. Coplanarity applies to the exposed heat sink slug as well as the
terminals.
3. Dimensions are in millimeters.

Figure 20. Marking Specifications
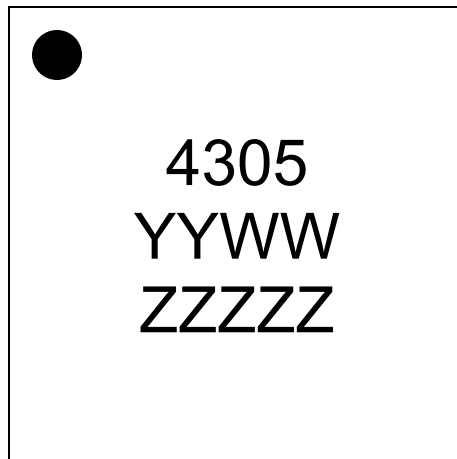
4305
YYWW
ZZZZZ

YYWW = Date Code
ZZZZZ = Last five digits of PSC Lot Number

Figure 21. Tape and Reel Drawing

Ao = 4.35 mm
Bo = 4.35 mm
Ko =   1.1 mm

Notes:
1. 10 sprocket hole pitch cumulative tolerance ±.02.
2. Camber not to exceed 1mm in 100mm.
3. Material: PS + C.
4. Ao and Bo measured as indicated.
5. Ko measured from a plane on the inside bottom of the pocket to the top surface of the carrier.
6. Pocket position relative to sprocket hole measured as true position of pocket, not pocket hole.

Table 10. Ordering Information

Order Code	Part Marking	Description	Package	Shipping Method
4305-00	PE4305-EK	PE4305-20MLP 4x4mm-EK	Evaluation Kit	1 / Box
4305-51	4305	PE4305G-20MLP 4x4mm-75A	Green 20-lead 4x4mm QFN	75 units / Tube
4305-52	4305	PE4305G-20MLP 4x4mm-3000C	Green 20-lead 4x4mm QFN	3000 units / T&R

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Data Sheet Identification

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The product is in a formative or design stage. The data sheet contains design target specifications for product development. Specifications and features may change in any manner without notice.

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The data sheet contains preliminary data. Additional data may be added at a later date. Peregrine reserves the right to change specifications at any time without notice in order to supply the best possible product.

Product Specification

The data sheet contains final data. In the event Peregrine decides to change the specifications, Peregrine will notify customers of the intended changes by issuing a DCN (Document Change Notice).

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